

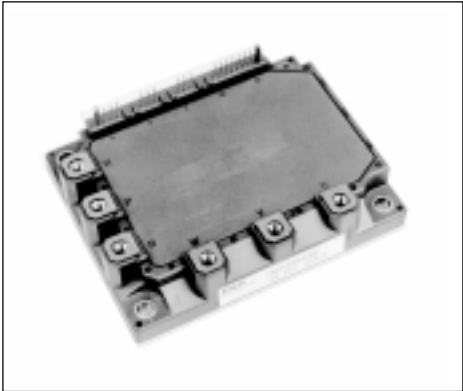
6MBP50RA120

IGBT-IPM R series

1200V / 50A 6 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

● Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item			Symbol	Rating		Unit
				Min.	Max.	
DC bus voltage			V _{DC}	0	900	V
DC bus voltage (surge)			V _{DC(surge)}	0	1000	V
DC bus voltage (short operating)			V _{SC}	200	800	V
Collector-Emitter voltage			V _{CES}	0	1200	V
INV	Collector current	DC	I _C	-	50	A
		1ms	I _{CP}	-	100	A
		DC	-I _C	-	50	A
	Collector power dissipation	One transistor	P _C	-	357	W
Junction temperature			T _J	-	150	°C
Input voltage of power supply for Pre-Driver			V _{CC} *1	0	20	V
Input signal voltage			V _{in} *2	0	V _Z	V
Input signal current			I _{in}	-	1	mA
Alarm signal voltage			V _{ALM} *3	0	V _{CC}	V
Alarm signal current			I _{ALM} *4	-	15	mA
Storage temperature			T _{stg}	-40	125	°C
Operating case temperature			T _{OP}	-20	100	°C
Isolating voltage (Case-Terminal)			V _{iso} *5	-	AC2.5	kV
Screw torque		Mounting (M5)		-	3.5 *6	N·m
		Terminal (M5)		-	3.5 *6	N·m

*1 Apply V_{CC} between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.
*2 Apply V_{in} between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.
*3 Apply V_{ALM} between terminal No. 16 and 10.
*4 Apply I_{ALM} to terminal No. 16.
*5 50Hz/60Hz sine wave 1 minute.
*6 Recommendable Value : 2.5 to 3.0 N·m

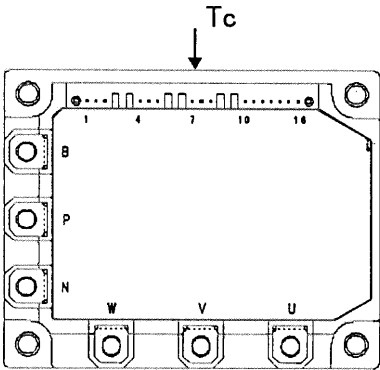


Fig.1 Measurement of case temperature

● Electrical characteristics of power circuit (at Tc=Tj=25°C, V_{CC}=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
INV	Collector current at off signal input	V _{CE} =1200V input terminal open	—	—	1.0	mA
	Collector-Emitter saturation voltage	I _c =50A	—	—	2.6	V
	Forward voltage of FWD	-I _c =50A	—	—	3.0	V

● **Electrical characteristics of control circuit**(at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	I_{ccp}	$f_{sw}=0$ to 15kHz $T_c=-20$ to 100°C *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	I_{ccn}	$f_{sw}=0$ to 15kHz $T_c=-20$ to 100°C *7	10	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_z	$R_{in}=20\text{k ohm}$	-	8.0	-	V
Over heating protection temperature level	T_{COH}	$V_{DC}=0\text{V}$, $I_c=0\text{A}$, Case temperature	110	-	125	$^\circ\text{C}$
Hysteresis	T_{CH}		-	20	-	$^\circ\text{C}$
IGBT chips over heating protection temperature level	T_{JOH}	surface of IGBT chips	150	-	-	$^\circ\text{C}$
Hysteresis	T_{JH}		-	20	-	$^\circ\text{C}$
Collector current protection level	INV	I_{OC}	$T_j=125^\circ\text{C}$	75	-	A
Over current protection delay time		t_{DOC}	$T_j=25^\circ\text{C}$ Fig.2	-	10	μs
Under voltage protection level		V_{UV}	11.0	-	12.5	V
Hysteresis		V_H	0.2	-	-	V
Alarm signal hold time		t_{ALM}	1.5	2	-	ms
SC protection delay time		t_{SC}	$T_j=25^\circ\text{C}$ Fig.3	-	-	μs
Limiting resistor for alarm		R_{ALM}	1425	1500	1575	ohm

*7 Switching frequency of IPM

● **Dynamic characteristics**(at $T_c=T_j=125^\circ\text{C}$, $V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	t_{on}	$I_C=50\text{A}$, $V_{DC}=600\text{V}$	0.3	-	-	μs
	t_{off}		-	-	3.6	μs
Switching time (FWD)	t_{rr}	$I_F=50\text{A}$, $V_{DC}=600\text{V}$	-	-	0.4	μs

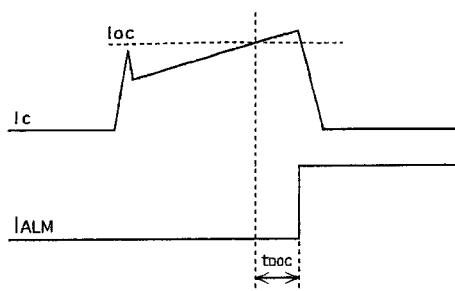


Fig.2 Definition of OC delay time

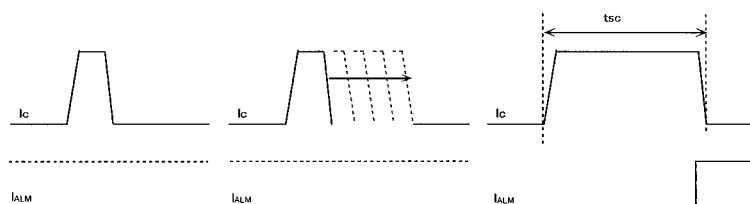


Fig.3 Definition of tsc

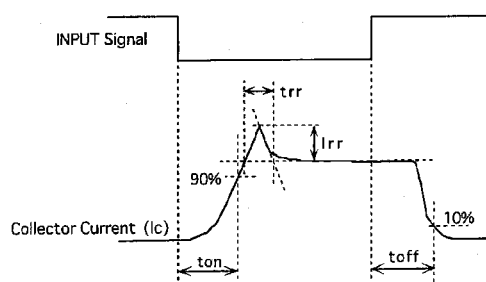


Fig.4 Definition of switching time

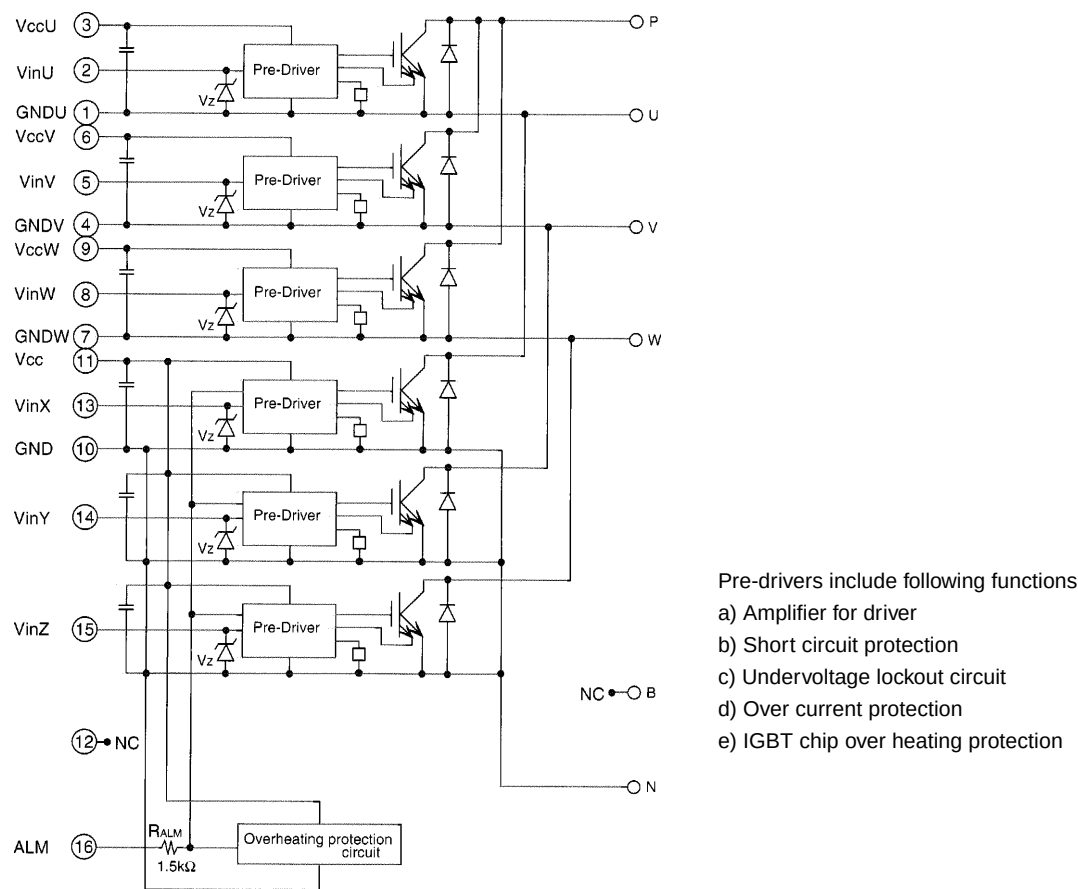
● **Thermal characteristics**($T_c=25^\circ\text{C}$)

Item			Symbol	Typ.	Max.	Unit
Junction to Case thermal resistance	INV	IGBT	$R_{th(j-c)}$	-	0.35	$^\circ\text{C/W}$
		FWD	$R_{th(j-c)}$	-	0.85	$^\circ\text{C/W}$
Case to fin thermal resistance with compound			$R_{th(c-f)}$	0.05	-	$^\circ\text{C/W}$

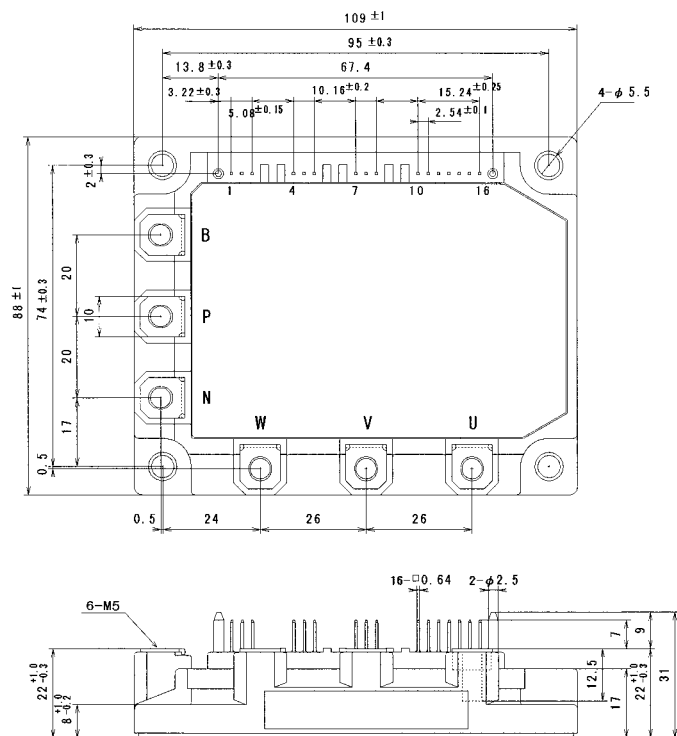
● **Recommendable value**

Item		Symbol	Min.	Typ.	Max.	Unit
DC bus voltage		V_{DC}	200	-	800	V
Operating power supply voltage range of Pre-driver		V_{CC}	13.5	15	16.5	V
Switching frequency of IPM		f_{sw}	1	-	20	kHz
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

Block diagram

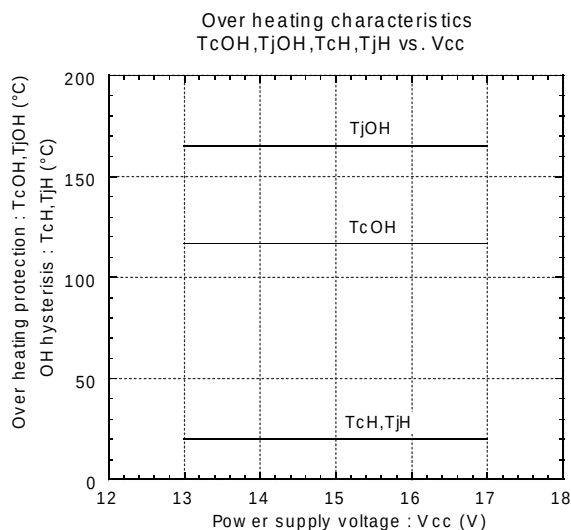
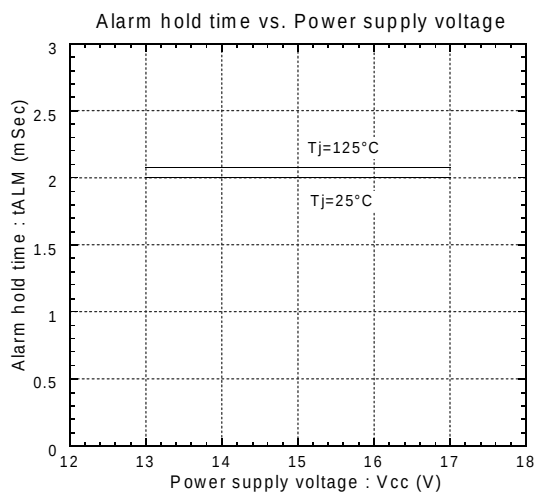
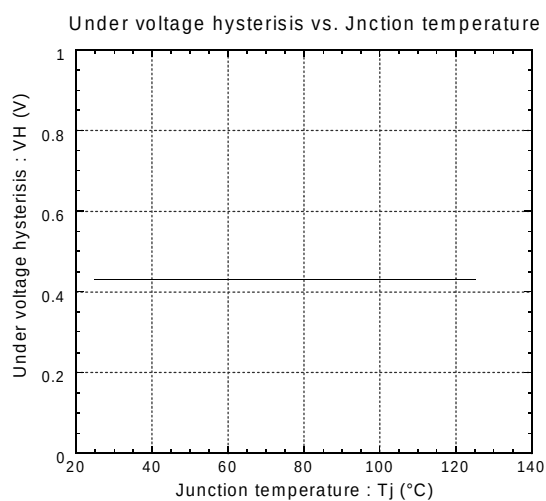
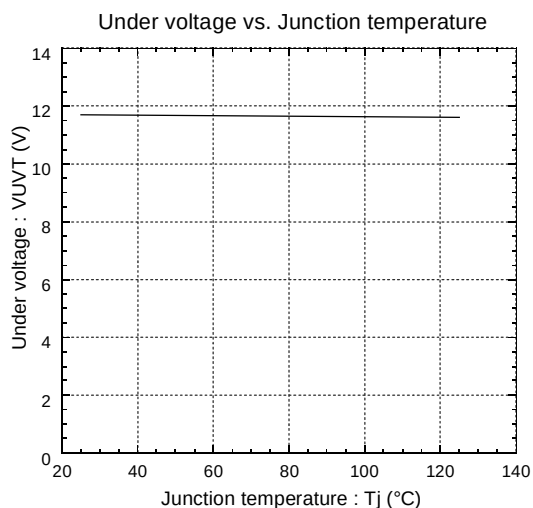
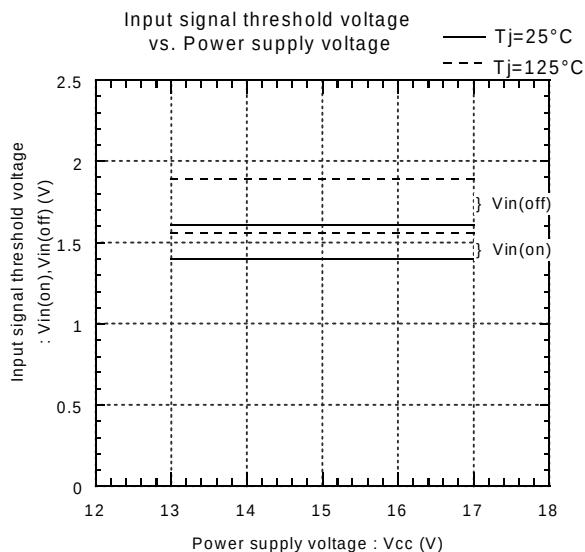
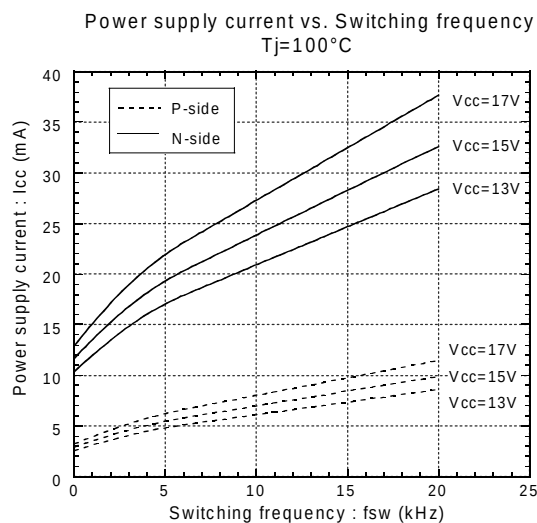


Outline drawings, mm



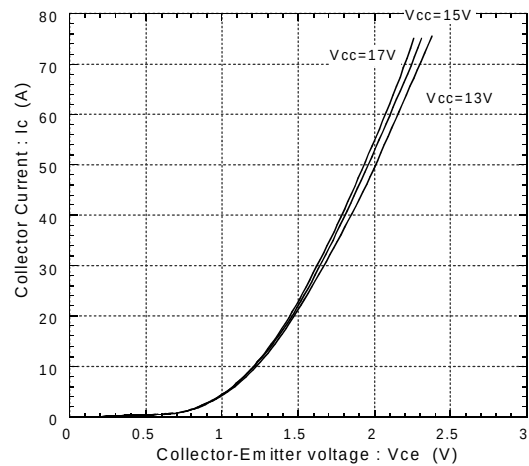
Characteristics (Representative)

Control Circuit

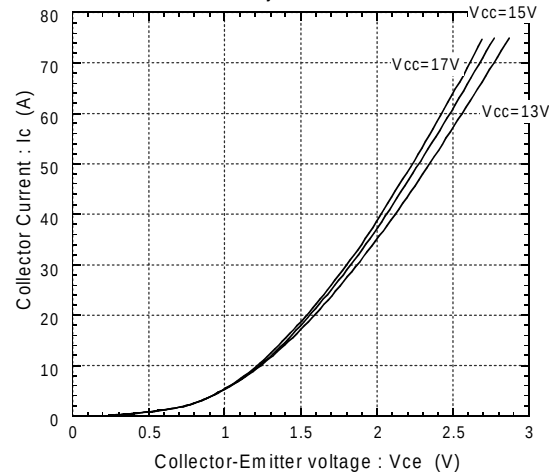


● Inverter

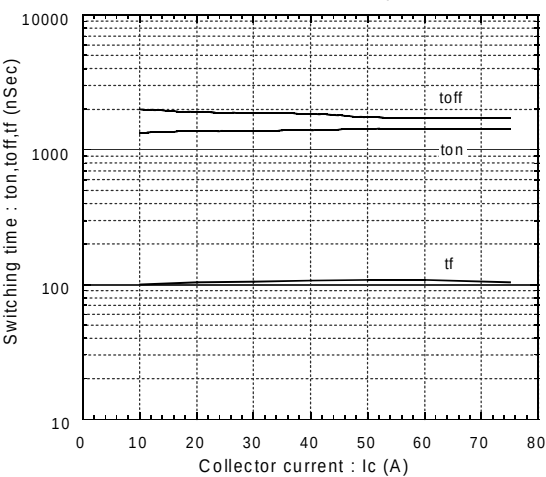
Collector current vs. Collector-Emitter voltage
Tj=25°C



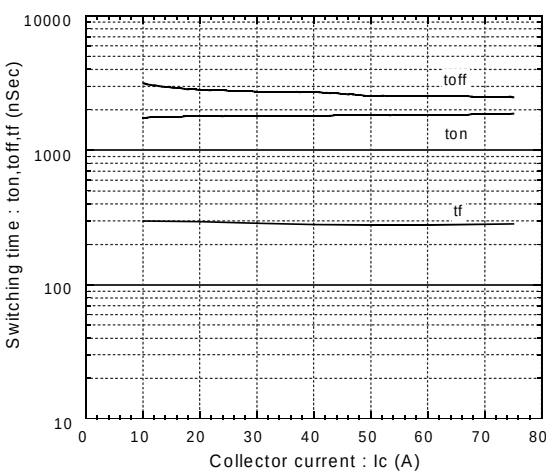
Collector current vs. Collector-Emitter voltage
Tj=125°C



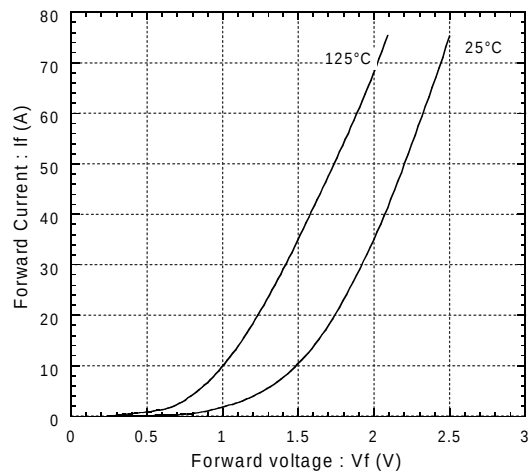
Switching time vs. Collector current
Edc=600V,Vcc=15V,Tj=25°C



Switching time vs. Collector current
Edc=600V,Vcc=15V,Tj=125°C



Forward current vs. Forward voltage



Reverse recovery characteristics
trr,Irr vs. IF

